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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC G4
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	867MHz
Co-Processors/DSP	Multimedia; SIMD
RAM Controllers	-
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	-
SATA	-
USB	-
Voltage - I/O	1.5V, 1.8V, 2.5V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	483-BCBGA, FCCBGA
Supplier Device Package	483-FCCBGA (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc7457vg867nc

- Four integer units (IUs) that share 32 GPRs for integer operands
  - Three identical IUs (IU1a, IU1b, and IU1c) can execute all integer instructions except multiply, divide, and move to/from special-purpose register instructions
  - IU2 executes miscellaneous instructions including the CR logical operations, integer multiplication and division instructions, and move to/from special-purpose register instructions
- Five-stage FPU and a 32-entry FPR file
  - Fully IEEE 754-1985 compliant FPU for both single- and double-precision operations
  - Supports non-IEEE mode for time-critical operations
  - Hardware support for denormalized numbers
  - Thirty-two 64-bit FPRs for single- or double-precision operands
- Four vector units and 32-entry vector register file (VRs)
  - Vector permute unit (VPU)
  - Vector integer unit 1 (VIU1) handles short-latency AltiVec™ integer instructions, such as vector add instructions (for example, **vaddsbs**, **vaddshs**, and **vaddsws**)
  - Vector integer unit 2 (VIU2) handles longer-latency AltiVec integer instructions, such as vector multiply add instructions (for example, **vmhaddshs**, **vmhraddshs**, and **vmladduhm**)
  - Vector floating-point unit (VFPU)
- Three-stage load/store unit (LSU)
  - Supports integer, floating-point, and vector instruction load/store traffic
  - Four-entry vector touch queue (VTQ) supports all four architected AltiVec data stream operations
  - Three-cycle GPR and AltiVec load latency (byte, half-word, word, vector) with one-cycle throughput
  - Four-cycle FPR load latency (single, double) with one-cycle throughput
  - No additional delay for misaligned access within double-word boundary
  - Dedicated adder calculates effective addresses (EAs)
  - Supports store gathering
  - Performs alignment, normalization, and precision conversion for floating-point data
  - Executes cache control and TLB instructions
  - Performs alignment, zero padding, and sign extension for integer data
  - Supports hits under misses (multiple outstanding misses)
  - Supports both big- and little-endian modes, including misaligned little-endian accesses

- Three issue queues FIQ, VIQ, and GIQ can accept as many as one, two, and three instructions, respectively, in a cycle. Instruction dispatch requires the following:
  - Instructions can be dispatched only from the three lowest IQ entries—IQ0, IQ1, and IQ2
  - A maximum of three instructions can be dispatched to the issue queues per clock cycle

Table 1. Microarchitecture Comparison (continued)

Microarchitectural Specs	MPC7457/MPC7447	MPC7455/MPC7445	MPC7450/MPC7451/ MPC7441
Minimum misprediction penalty	6	6	6
Execution Unit Timings (Latency-Throughput)			
Aligned load (integer, float, vector)	3-1, 4-1, 3-1	3-1, 4-1, 3-1	3-1, 4-1, 3-1
Misaligned load (integer, float, vector)	4-2, 5-2, 4-2	4-2, 5-2, 4-2	4-2, 5-2, 4-2
L1 miss, L2 hit latency	9 data/13 instruction	9 data/13 instruction	9 data/13 instruction
SFX (aDd Sub, Shift, Rot, Cmp, logicals)	1-1	1-1	1-1
Integer multiply (32 × 8, 32 × 16, 32 × 32)	3-1, 3-1, 4-2	3-1, 3-1, 4-2	3-1, 3-1, 4-2
Scalar float	5-1	5-1	5-1
VSFX (vector simple)	1-1	1-1	1-1
VCFX (vector complex)	4-1	4-1	4-1
VFPU (vector float)	4-1	4-1	4-1
VPER (vector permute)	2-1	2-1	2-1
MMUs			
TLBs (instruction and data)	128-entry, 2-way	128-entry, 2-way	128-entry, 2-way
Tablewalk mechanism	Hardware + software	Hardware + software	Hardware + software
Instruction BATs/data BATs	8/8	8/8	4/4
L1 I Cache/D Cache Features			
Size	32K/32K	32K/32K	32K/32K
Associativity	8-way	8-way	8-way
Locking granularity	Way	Way	Way
Parity on I cache	Word	Word	Word
Parity on D cache	Byte	Byte	Byte
Number of D cache misses (load/store)	5/1	5/1	5/1
Data stream touch engines	4 streams	4 streams	4 streams
On-Chip Cache Features			
Cache level	L2	L2	L2
Size/associativity	512-Kbyte/8-way	256-Kbyte/8-way	256-Kbyte/8-way
Access width	256 bits	256 bits	256 bits
Number of 32-byte sectors/line	2	2	2
Parity	Byte	Byte	Byte
Off-Chip Cache Support [1]			

Table 4 provides the recommended operating conditions for the MPC7457.

Table 4. Recommended Operating Conditions [1]

Characteristic		Symbol	Recommended Value		Unit	Notes
			Min	Max		
Core supply voltage		V_{DD}	1.3 V ± 50 mV		V	
PLL supply voltage		AV_{DD}	1.3 V ± 50 mV		V	2
Processor bus supply voltage	BVSEL = 0	OV_{DD}	1.8 V ± 5%		V	
	BVSEL = $\overline{\text{HRESET}}$ or OV_{DD}	OV_{DD}	2.5 V ± 5%		V	
L3 bus supply voltage	L3VSEL = 0	GV_{DD}	1.8 V ± 5%		V	
	L3VSEL = $\overline{\text{HRESET}}$ or GV_{DD}	GV_{DD}	2.5 V ± 5%		V	
	L3VSEL = ¬$\overline{\text{HRESET}}$	GV_{DD}	1.5 V ± 5%		V	3
Input voltage	Processor bus	V_{in}	GND	OV_{DD}	V	
	L3 bus	V_{in}	GND	GV_{DD}	V	
	JTAG signals	V_{in}	GND	OV_{DD}	V	
Die-junction temperature		T_j	0	105	°C	

Notes:

1. These are the recommended and tested operating conditions. Proper device operation outside of these conditions is not guaranteed.
2. This voltage is the input to the filter discussed in Section 9.2, “PLL Power Supply Filtering,” and not necessarily the voltage at the AV_{DD} pin, which may be reduced from V_{DD} by the filter.
3. ¬$\overline{\text{HRESET}}$ is the inverse of $\overline{\text{HRESET}}$.

Table 5 provides the package thermal characteristics for the MPC7457.

Table 5. Package Thermal Characteristics [1]

Characteristic	Symbol	Value		Unit	Notes
		MPC7447	MPC7457		
Junction-to-ambient thermal resistance, natural convection	$R_{\theta JA}$	22	20	°C/W	2, 3
Junction-to-ambient thermal resistance, natural convection, four-layer (2s2p) board	$R_{\theta JMA}$	14	14	°C/W	2, 4
Junction-to-ambient thermal resistance, 200 ft/min airflow, single-layer (1s) board	$R_{\theta JMA}$	16	15	°C/W	2, 4
Junction-to-ambient thermal resistance, 200 ft/min airflow, four-layer (2s2p) board	$R_{\theta JMA}$	11	11	°C/W	2, 4
Junction-to-board thermal resistance	$R_{\theta JB}$	6	6	°C/W	5
Junction-to-case thermal resistance	$R_{\theta JC}$	<0.1	<0.1	°C/W	6

Table 5. Package Thermal Characteristics [1] (continued)

Characteristic	Symbol	Value		Unit	Notes
		MPC7447	MPC7457		
Coefficient of thermal expansion		6.8	6.8	ppm/°C	

Notes:
1. Refer to Section 9.8, "Thermal Management Information," for more details about thermal management.
2. Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, airflow, power dissipation of other components on the board, and board thermal resistance.
3. Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board horizontal.
4. Per JEDEC JESD51-6 with the board horizontal.
5. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
6. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the calculated case temperature. The actual value of $R_{\theta JC}$ for the part is less than 0.1°C/W.

Table 6 provides the DC electrical characteristics for the MPC7457.

Table 6. DC Electrical Specifications

At recommended operating conditions. See Table 4.

Characteristic	Nominal Bus Voltage [1]	Symbol	Min	Max	Unit	Notes
Input high voltage (all inputs including SYSCLK)	1.5	V_{IH}	$GV_{DD} \times 0.65$	$GV_{DD} + 0.3$	V	2
	1.8		$OV_{DD}/GV_{DD} \times 0.65$	$OV_{DD}/GV_{DD} + 0.3$	V	
	2.5		1.7	$OV_{DD}/GV_{DD} + 0.3$	V	
Input low voltage (all inputs including SYSCLK)	1.5	V_{IL}	–0.3	$GV_{DD} \times 0.35$	V	2, 6
	1.8		–0.3	$OV_{DD}/GV_{DD} \times 0.35$	V	
	2.5		–0.3	0.7	V	
Input leakage current, $V_{in} = GV_{DD}/OV_{DD}$	—	I_{in}	—	30	µA	2, 3
High-impedance (off-state) leakage current, $V_{in} = GV_{DD}/OV_{DD}$	—	I_{TSI}	—	30	µA	2, 3, 4
Output high voltage, $I_{OH} = –5$ mA	1.5	V_{OH}	$OV_{DD}/GV_{DD} – 0.45$	—	V	6
	1.8		$OV_{DD}/GV_{DD} – 0.45$	—	V	
	2.5		1.8	—	V	
Output low voltage, $I_{OL} = 5$ mA	1.5	V_{OL}	—	0.45	V	6
	1.8		—	0.45	V	
	2.5		—	0.6	V	

Table 8. Clock AC Timing Specifications (continued)

At recommended operating conditions. See Table 4.

Characteristic	Symbol	Maximum Processor Core Frequency								Unit	Notes
		867 MHz		1000 MHz		1200 MHz		1267 MHz			
		Min	Max	Min	Max	Min	Max	Min	Max		
Internal PLL relock time		—	100	—	100	—	100	—	100	µs	7

Notes:

1. **Caution**: The SYSCLK frequency and PLL_CFG[0:4] settings must be chosen such that the resulting SYSCLK (bus) frequency, CPU (core) frequency, and PLL (VCO) frequency do not exceed their respective maximum or minimum operating frequencies. Refer to the PLL_CFG[0:4] signal description in Section 1.9.1, “PLL Configuration,” for valid PLL_CFG[0:4] settings.
2. Assumes lightly-loaded, single-processor system; see Section 5.2.1, “Clock AC Specifications” for more information.
3. Rise and fall times for the SYSCLK input measured from 0.4 to 1.4 V.
4. Timing is guaranteed by design and characterization.
5. Guaranteed by design.
6. The SYSCLK driver’s closed loop jitter bandwidth should be less than 1.5 MHz at –3 dB.
7. Relock timing is guaranteed by design and characterization. PLL-relock time is the maximum amount of time required for PLL lock after a stable V_{DD} and SYSCLK are reached during the power-on reset sequence. This specification also applies when the PLL has been disabled and subsequently re-enabled during sleep mode. Also note that $\overline{\text{HRESET}}$ must be held asserted for a minimum of 255 bus clocks after the PLL-relock time during the power-on reset sequence.

Figure 3 provides the SYSCLK input timing diagram.

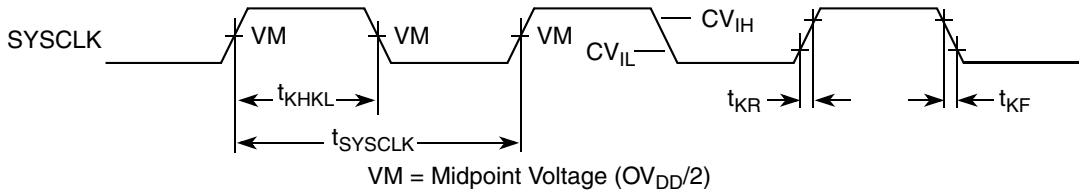


Figure 3. SYSCLK Input Timing Diagram

5.2.2 Processor Bus AC Specifications

Table 9 provides the processor bus AC timing specifications for the MPC7457 as defined in Figure 4 and Figure 5. Timing specifications for the L3 bus are provided in Section 5.2.3, “L3 Clock AC Specifications.”

Table 9. Processor Bus AC Timing Specifications [1] (continued)

At recommended operating conditions. See Table 4.

Parameter	Symbol [2]	All Revisions and Speed Grades		Unit	Notes
		Min	Max		
SYSCLK to $\overline{\text{ARTRY}}$/$\overline{\text{SHD0}}$/$\overline{\text{SHD1}}$ high impedance after precharge	t_{KHARPZ}	—	2	t_{SYSCLK}	3, 5, 6, 7

Notes:

1. All input specifications are measured from the midpoint of the signal in question to the midpoint of the rising edge of the input SYSCLK. All output specifications are measured from the midpoint of the rising edge of SYSCLK to the midpoint of the signal in question. All output timings assume a purely resistive 50-Ω load (see Figure 4). Input and output timings are measured at the pin; time-of-flight delays must be added for trace lengths, vias, and connectors in the system.
2. The symbology used for timing specifications herein follows the pattern of $t_{\text{(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(reference)(state)(signal)(state)}}$ for outputs. For example, t_{IVKH} symbolizes the time input signals (I) reach the valid state (V) relative to the SYSCLK reference (K) going to the high (H) state or input setup time. And t_{KHOV} symbolizes the time from SYSCLK(K) going high (H) until outputs (O) are valid (V) or output valid time. Input hold time can be read as the time that the input signal (I) went invalid (X) with respect to the rising clock edge (KH) (note the position of the reference and its state for inputs) and output hold time can be read as the time from the rising edge (KH) until the output went invalid (OX).
3. t_{sysclk} is the period of the external clock (SYSCLK) in ns. The numbers given in the table must be multiplied by the period of SYSCLK to compute the actual time duration (in ns) of the parameter in question.
4. According to the bus protocol, $\overline{\text{TS}}$ is driven only by the currently active bus master. It is asserted low then precharged high before returning to high impedance as shown in Figure 6. The nominal precharge width for $\overline{\text{TS}}$ is 0.5 × t_{SYSCLK}, that is, less than the minimum t_{SYSCLK} period, to ensure that another master asserting $\overline{\text{TS}}$ on the following clock will not contend with the precharge. Output valid and output hold timing is tested for the signal asserted. Output valid time is tested for precharge.The high-impedance behavior is guaranteed by design.
5. Guaranteed by design and not tested.
6. According to the bus protocol, $\overline{\text{ARTRY}}$ can be driven by multiple bus masters through the clock period immediately following $\overline{\text{AACK}}$. Bus contention is not an issue because any master asserting $\overline{\text{ARTRY}}$ will be driving it low. Any master asserting it low in the first clock following $\overline{\text{AACK}}$ will then go to high impedance for one clock before precharging it high during the second cycle after the assertion of $\overline{\text{AACK}}$. The nominal precharge width for $\overline{\text{ARTRY}}$ is 1.0 t_{SYSCLK}; that is, it should be high impedance as shown in Figure 6 before the first opportunity for another master to assert $\overline{\text{ARTRY}}$. Output valid and output hold timing is tested for the signal asserted.The high-impedance behavior is guaranteed by design.
7. According to the MPX bus protocol, $\overline{\text{SHD0}}$ and $\overline{\text{SHD1}}$ can be driven by multiple bus masters beginning the cycle of $\overline{\text{TS}}$. Timing is the same as $\overline{\text{ARTRY}}$, that is, the signal is high impedance for a fraction of a cycle, then negated for up to an entire cycle (crossing a bus cycle boundary) before being three-stated again. The nominal precharge width for $\overline{\text{SHD0}}$ and $\overline{\text{SHD1}}$ is 1.0 t_{SYSCLK}. The edges of the precharge vary depending on the programmed ratio of core to bus (PLL configurations).
8. $\overline{\text{BMODE}}$[0:1] and BVSEL are mode select inputs and are sampled before and after $\overline{\text{HRESET}}$ negation. These parameters represent the input setup and hold times for each sample. These values are guaranteed by design and not tested. These inputs must remain stable after the second sample. See Figure 5 for sample timing.

Figure 4 provides the AC test load for the MPC7457.

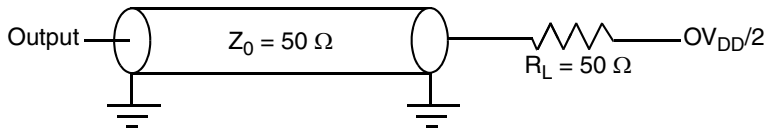


Figure 4. AC Test Load

Table 10. L3_CLK Output AC Timing Specifications (continued)

At recommended operating conditions. See Table 4.

Parameter	Symbol	Device Revision (L3 I/O Voltage) [6]						Unit	Notes
		Rev 1.1. (All I/O Modes) Rev 1.2 (1.5-V I/O Mode)			Rev 1.2 (1.8-, 2.5-V I/O Modes)				
		Min	Typ	Max	Min	Typ	Max		
L3 clock jitter		—	—	± 75	—	—	± 75	ps	5

Notes:

1. The maximum L3 clock frequency (and minimum L3 clock period) will be system dependent. See Section 5.2.3, "L3 Clock AC Specifications," for an explanation that this maximum frequency is not functionally tested at speed by Freescale. The minimum L3 clock frequency and period are f_{SYSCLK} and t_{SYSCLK}, respectively.
2. The nominal duty cycle of the L3 output clocks is 50% measured at midpoint voltage.
3. Maximum possible skew between L3_CLK0 and L3_CLK1. This parameter is critical to the address and control signals which are common to both SRAM chips in the L3.
4. Maximum possible skew between L3_CLK0 and L3_ECHO_CLK1 or between L3_CLK1 and L3_ECHO_CLK3 for PB2 or Late Write SRAM. This parameter is critical to the read data signals because the processor uses the feedback loop to latch data driven from the SRAM, each of which drives data based on L3_CLK0 or L3_CLK1.
5. Guaranteed by design and not tested. The input jitter on SYSCLK affects L3 output clocks and the L3 address, data, and control signals equally and, therefore, is already comprehended in the AC timing and does not have to be considered in the L3 timing analysis. The clock-to-clock jitter shown here is uncertainty in the internal clock period caused by supply voltage noise or thermal effects. This is also comprehended in the AC timing specifications and need not be considered in the L3 timing analysis.
6. L3 I/O voltage mode must be configured by L3VSEL as described in Table 3, and voltage supplied at GV_{DD} must match mode selected as specified in Table 4. See Table 22 for revision level information and part marking.

The L3_CLK timing diagram is shown in Figure 7.

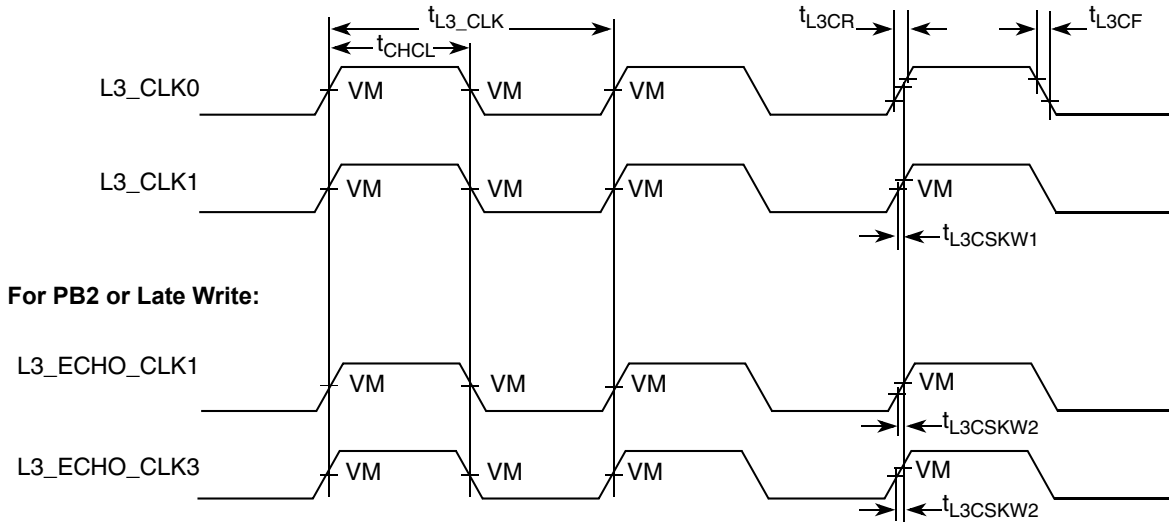


Figure 7. L3_CLK_OUT Output Timing Diagram

5.2.4 L3 Bus AC Specifications

The MPC7457 L3 interface supports three different types of SRAM: source-synchronous, double data rate (DDR) MSUG2 SRAM, Late Write SRAMs, and pipeline burst (PB2) SRAMs. Each requires a different protocol on the L3 interface and a different routing of the L3 clock signals. The type of SRAM is programmed in L3CR[22:23] and the MPC7457 then follows the appropriate protocol for that type. The designer must connect and route the L3 signals appropriately for each type of SRAM. Following are some observations about the L3 interface.

- The routing for the point-to-point signals (L3_CLK[0:1], L3DATA[0:63], L3DP[0:7], and L3_ECHO_CLK[0:3]) to a particular SRAM must be delay matched.
- For 1-Mbyte of SRAM, use L3_ADDR[16:0] (L3_ADDR[0] is LSB)
- For 2-Mbyte of SRAM, use L3_ADDR[17:0] (L3_ADDR[0] is LSB)
- For 4-Mbyte of SRAM, use L3_ADDR[18:0] (L3_ADDR[0] is LSB)
- No pull-up resistors are required for the L3 interface
- For high-speed operations, L3 interface address and control signals should be a ‘T’ with minimal stubs to the two loads; data and clock signals should be point-to-point to their single load. Figure 8 shows the AC test load for the L3 interface.

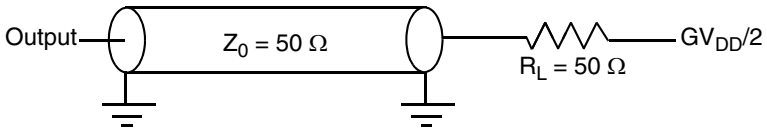


Figure 8. AC Test Load for the L3 Interface

In general, if routing is short, delay-matched, and designed for incident wave reception and minimal reflection, there is a high probability that the AC timing of the MPC7457 L3 interface will meet the maximum frequency operation of appropriately chosen SRAMs. This is despite the pessimistic, guard-banded AC specifications (see Table 12, Table 13, and Table 14), the limitations of functional testers described in Section 5.2.3, “L3 Clock AC Specifications,” and the uncertainty of clocks and signals which inevitably make worst-case critical path timing analysis pessimistic.

More specifically, certain signals within groups should be delay-matched with others in the same group while intergroup routing is less critical. Only the address and control signals are common to both SRAMs and additional timing margin is available for these signals. The double-clocked data signals are grouped with individual clocks as shown in Figure 9 or Figure 11, depending on the type of SRAM. For example, for the MSUG2 DDR SRAM (see Figure 9); L3DATA[0:31], L3DP[0:3], and L3_CLK[0] form a closely coupled group of outputs from the MPC7457; while L3DATA[0:15], L3DP[0:1], and L3_ECHO_CLK[0] form a closely coupled group of inputs.

The *MPC7450 RISC Microprocessor Family User’s Manual* refers to logical settings called ‘sample points’ used in the synchronization of reads from the receive FIFO. The computation of the correct value for this setting is system-dependent and is described in the *MPC7450 RISC Microprocessor Family User’s Manual*. Three specifications are used in this calculation and are given in Table 11. It is essential that all three specifications are included in the calculations to determine the sample points, as incorrect settings can result in errors and unpredictable behavior. For more information, see the *MPC7450 RISC Microprocessor Family User’s Manual.*

Table 12. Effect of L3OHCR Settings on L3 Bus AC Timing (continued)

At recommended operating conditions. See Table 4.

Field Name[1]	Affected Signals	Value	Output Valid Time		Output Hold Time		Unit	Notes
			Parameter Symbol [2]	Change [3]	Parameter Symbol [2]	Change [3]		
L3CLK*n*_OH	All signals latched by SRAM connected to L3_CLK*n*	0b000	t_{L3CHOV}, t_{L3CHDV}, t_{L3CLDV}	0	t_{L3CHOX}, t_{L3CHDX}, t_{L3CLDX}	0	ps	4
		0b001		– 50		– 50		5
		0b010		– 100		– 100		5
		0b011		– 150		– 150		5
		0b100		– 200		– 200		5
		0b101		– 250		– 250		5
		0b110		– 300		– 300		5
		0b111		– 350		– 350		5
L3DOH*n*	L3_DATA[*n*:*n*+7], L3_DP[*n*/8]	0b000	t_{L3CHDV}, t_{L3CLDV}	0	t_{L3CHDX}, t_{L3CLDX}	0	ps	4
		0b001		+ 50		+ 50		
		0b010		+ 100		+ 100		
		0b011		+ 150		+ 150		
		0b100		+ 200		+ 200		
		0b101		+ 250		+ 250		
		0b111		+ 300		+ 300		
		0b111		+ 350		+ 350		

Notes:

1. See the *MPC7450 RISC Microprocessor Family User's Manual* for specific information regarding L3OHCR.
2. See Table 13 and Table 14 for more information.
3. Approximate delay verified by simulation; not tested or characterized.
4. Default value.
5. Increasing values of L3CLK*n*_OH delay the L3_CLK*n* signal, effectively decreasing the output valid and output hold times of all signals latched relative to that clock signal by the SRAM; see Figure 9 and Figure 11.

5.2.4.2 L3 Bus AC Specifications for DDR MSUG2 SRAMs

When using DDR MSUG2 SRAMs at the L3 interface, the parts should be connected as shown in Figure 9. Outputs from the MPC7457 are actually launched on the edges of an internal clock phase-aligned to SYSCLK (adjusted for core and L3 frequency divisors). L3_CLK0 and L3_CLK1 are this internal clock output with 90° phase delay, so outputs are shown synchronous to L3_CLK0 and L3_CLK1. Output valid times are typically negative when referenced to L3_CLK*n* because the data is launched one-quarter period before L3_CLK*n* to provide adequate setup time at the SRAM after the delay-matched address, control, data, and L3_CLK*n* signals have propagated across the printed-wiring board.

Inputs to the MPC7457 are source-synchronous with the CQ clock generated by the DDR MSUG2 SRAMs. These CQ clocks are received on the L3_ECHO_CLK*n* inputs of the MPC7457. An internal circuit delays the incoming L3_ECHO_CLK*n* signal such that it is positioned within the valid data

Table 14. L3 Bus Interface AC Timing Specifications for PB2 and Late Write SRAMs

At recommended operating conditions. See Table 4.

Parameter	Symbol	All Revisions and L3 I/O Voltage Modes		Unit	Notes
		Min	Max		
L3_CLK rise and fall time	t_{L3CR}, t_{L3CF}	—	0.75	ns	1, 2
Setup times: Data and parity	t_{L3DVEH}	0.1	—	ns	2, 3
Input hold times: Data and parity	t_{L3DXEH}	0.7	—	ns	2, 3
Valid times: Data and parity	t_{L3CHDV}	—	2.5	ns	2, 4, 5
Valid times: All other outputs	t_{L3CHOV}	—	1.8	ns	5
Output hold times: Data and parity	t_{L3CHDX}	1.4	—	ns	2, 4, 5
Output hold times: All other outputs	t_{L3CHOX}	1.0	—	ns	2, 5
L3_CLK to high impedance: Data and parity	t_{L3CHDZ}	—	3.0	ns	2
L3_CLK to high impedance: All other outputs	t_{L3CHOZ}	—	3.0	ns	2

Notes:

1. Rise and fall times for the L3_CLK output are measured from 20% to 80% of GV_{DD}.
2. Timing behavior and characterization are currently being evaluated.
3. All input specifications are measured from the midpoint of the signal in question to the midpoint voltage of the rising edge of the input L3_ECHO_CLK*n* (see Figure 10). Input timings are measured at the pins.
4. All output specifications are measured from the midpoint voltage of the rising edge of L3_CLK*n* to the midpoint of the signal in question. The output timings are measured at the pins. All output timings assume a purely resistive 50-Ω load (see Figure 10).
5. Assumes default value of L3OHCR. See Section 5.2.4.1, “Effects of L3OHCR Settings on L3 Bus AC Specifications,” for more information.

Table 17. Pinout Listing for the MPC7457, 483 CBGA Package (continued)

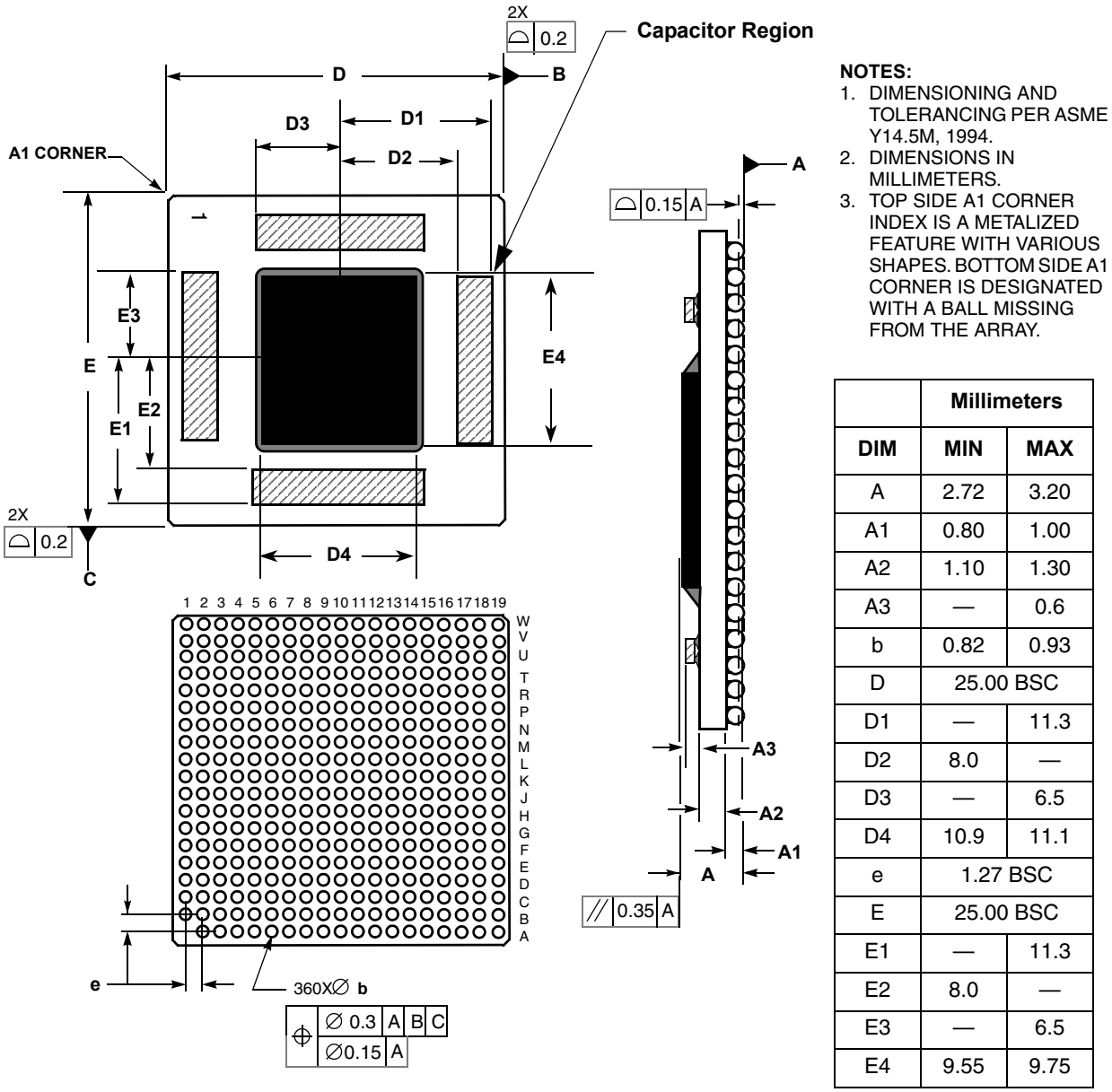
Signal Name	Pin Number	Active	I/O	I/F Select [1]	Notes
AV_{DD}	B2	—	Input	N/A	
$\overline{BG}$	R3	Low	Input	BVSEL	
$\overline{BMODE0}$	C6	Low	Input	BVSEL	4
$\overline{BMODE1}$	C4	Low	Input	BVSEL	5
$\overline{BR}$	K1	Low	Output	BVSEL	
BVSEL	G6	High	Input	N/A	6, 7
$\overline{CI}$	R1	Low	Output	BVSEL	
$\overline{CKSTP\_IN}$	F3	Low	Input	BVSEL	
$\overline{CKSTP\_OUT}$	K6	Low	Output	BVSEL	
CLK_OUT	N1	High	Output	BVSEL	
D[0:63]	AB15, T14, R14, AB13, V14, U14, AB14, W16, AA11, Y11, U12, W13, Y14, U13, T12, W12, AB12, R12, AA13, AB11, Y12, V11, T11, R11, W10, T10, W11, V10, R10, U10, AA10, U9, V7, T8, AB4, Y6, AB7, AA6, Y8, AA7, W8, AB10, AA16, AB16, AB17, Y18, AB18, Y16, AA18, W14, R13, W15, AA14, V16, W6, AA12, V6, AB9, AB6, R7, R9, AA9, AB8, W9	High	I/O	BVSEL	
$\overline{DBG}$	V1	Low	Input	BVSEL	
DP[0:7]	AA2, AB3, AB2, AA8, R8, W5, U8, AB5	High	I/O	BVSEL	
$\overline{DRDY}$	T6	Low	Output	BVSEL	8
DTI[0:3])	P2, T5, U3, P6	High	Input	BVSEL	9
EXT_QUAL	B9	High	Input	BVSEL	10
$\overline{GBL}$	M4	Low	I/O	BVSEL	
GND	A22, B1, B5, B12, B14, B16, B18, B20, C3, C9, C21, D7, D13, D15, D17, D19, E2, E5, E21, F10, F12, F14, F16, F19, G4, G7, G17, G21, H13, H15, H19, H5, J3, J10, J12, J14, J17, J21, K5, K9, K11, K13, K15, K19, L10, L12, L14, L17, L21, M3, M6, M9, M11, M13, M19, N10, N12, N14, N17, N21, P3, P9, P11, P13, P15, P19, R17, R21, T13, T15, T19, T4, T7, T9, U17, U21, V2, V5, V8, V12, V15, V19, W7, W17, W21, Y3, Y9, Y13, Y15, Y20, AA5, AA17, AB1, AB22	—	—	N/A	
GV_{DD}	B13, B15, B17, B19, B21, D12, D14, D16, D18, D21, E19, F13, F15, F17, F21, G19, H12, H14, H17, H21, J19, K17, K21, L19, M17, M21, N19, P17, P21, R15, R19, T17, T21, U19, V17, V21, W19, Y21	—	—	N/A	11
$\overline{HIT}$	K2	Low	Output	BVSEL	8
$\overline{HRESET}$	A3	Low	Input	BVSEL	
$\overline{INT}$	J6	Low	Input	BVSEL	

Table 17. Pinout Listing for the MPC7457, 483 CBGA Package (continued)

Signal Name	Pin Number	Active	I/O	I/F Select [1]	Notes
L1_TSTCLK	H4	High	Input	BVSEL	10
L2_TSTCLK	J2	High	Input	BVSEL	12
L3VSEL	A4	High	Input	N/A	6, 7
L3ADDR[18:0]	H11, F20, J16, E22, H18, G20, F22, G22, H20, K16, J18, H22, J20, J22, K18, K20, L16, K22, L18	High	Output	L3VSEL	
L3_CLK[0:1]	V22, C17	High	Output	L3VSEL	
$\overline{\text{L3\_CNTL}}$[0:1]	L20, L22	Low	Output	L3VSEL	
L3DATA[0:63]	AA19, AB20, U16, W18, AA20, AB21, AA21, T16, W20, U18, Y22, R16, V20, W22, T18, U20, N18, N20, N16, N22, M16, M18, M20, M22, R18, T20, U22, T22, R20, P18, R22, M15, G18, D22, E20, H16, C22, F18, D20, B22, G16, A21, G15, E17, A20, C19, C18, A19, A18, G14, E15, C16, A17, A16, C15, G13, C14, A14, E13, C13, G12, A13, E12, C12	High	I/O	L3VSEL	
L3DP[0:7]	AB19, AA22, P22, P16, C20, E16, A15, A12	High	I/O	L3VSEL	
L3_ECHO_CLK[0,2]	V18, E18	High	Input	L3VSEL	
L3_ECHO_CLK[1,3]	P20, E14	HIgh	I/O	L3VSEL	
$\overline{\text{LSSD\_MODE}}$	F6	Low	Input	BVSEL	7, 13
$\overline{\text{MCP}}$	B8	Low	Input	BVSEL	
No Connect	A8, A11, B6, B11, C11, D11, D3, D5, E11, E7, F2, F11, G2, H9	—	—	N/A	14
OV_{DD}	B3, C5, C7, C10, D2, E3, E9, F5, G3, G9, H7, J5, K3, L7, M5, N3, P7, R4, T3, U5, U7, U11, U15, V3, V9, V13, Y2, Y5, Y7, Y10, Y17, Y19, AA4, AA15	—	—	N/A	
PLL_CFG[0:4]	A2, F7, C2, D4, H8	High	Input	BVSEL	
$\overline{\text{PMON\_IN}}$	E6	Low	Input	BVSEL	15
$\overline{\text{PMON\_OUT}}$	B4	Low	Output	BVSEL	
$\overline{\text{QACK}}$	K7	Low	Input	BVSEL	
$\overline{\text{QREQ}}$	Y1	Low	Output	BVSEL	
$\overline{\text{SHD}}$[0:1]	L4, L8	Low	I/O	BVSEL	3
$\overline{\text{SMI}}$	G8	Low	Input	BVSEL	
$\overline{\text{SRESET}}$	G1	Low	Input	BVSEL	
SYSCLK	D6	—	Input	BVSEL	
$\overline{\text{TA}}$	N8	Low	Input	BVSEL	
TBEN	L3	High	Input	BVSEL	
$\overline{\text{TBST}}$	B7	Low	Output	BVSEL	
TCK	J7	High	Input	BVSEL	

8.2 Mechanical Dimensions for the MPC7447, 360 CBGA

Figure 20 provides the mechanical dimensions and bottom surface nomenclature for the MPC7447, 360 CBGA package.



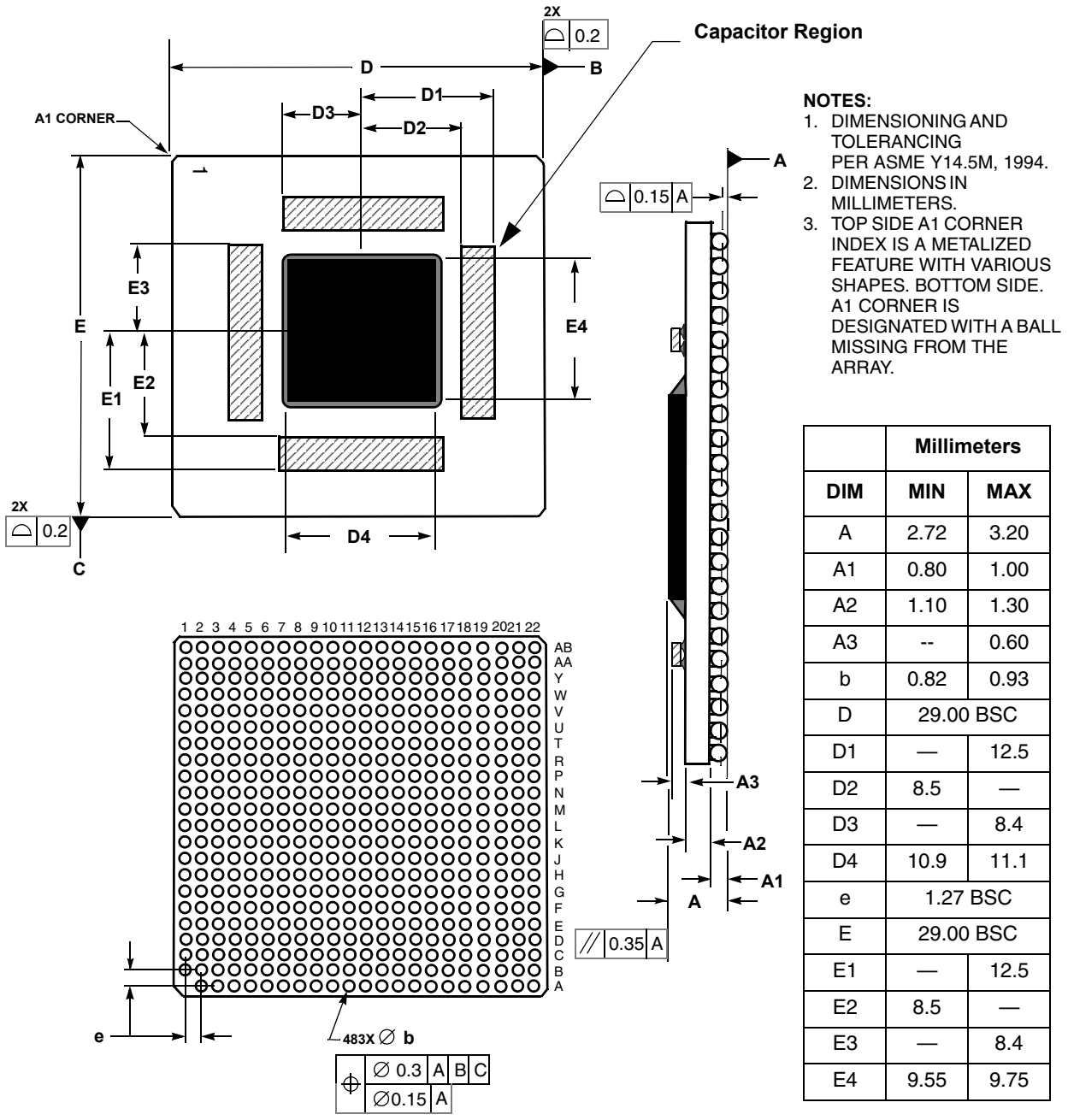
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS IN MILLIMETERS.
3. TOP SIDE A1 CORNER INDEX IS A METALIZED FEATURE WITH VARIOUS SHAPES. BOTTOM SIDE A1 CORNER IS DESIGNATED WITH A BALL MISSING FROM THE ARRAY.

	Millimeters	
DIM	MIN	MAX
A	2.72	3.20
A1	0.80	1.00
A2	1.10	1.30
A3	—	0.6
b	0.82	0.93
D	25.00 BSC	
D1	—	11.3
D2	8.0	—
D3	—	6.5
D4	10.9	11.1
e	1.27 BSC	
E	25.00 BSC	
E1	—	11.3
E2	8.0	—
E3	—	6.5
E4	9.55	9.75

Figure 20. Mechanical Dimensions and Bottom Surface Nomenclature for the MPC7447, 360 CBGA Package

8.5 Mechanical Dimensions for the MPC7457, 483 CBGA or RoHS BGA

Figure 22 provides the mechanical dimensions and bottom surface nomenclature for the MPC7457, 483 CBGA package.



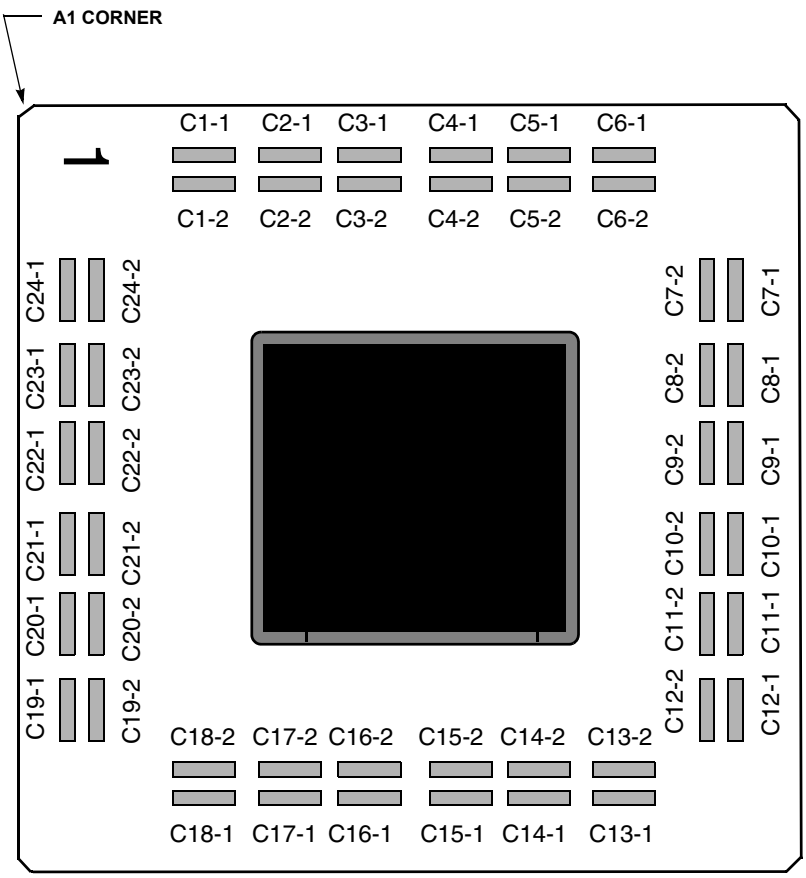
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS IN MILLIMETERS.
3. TOP SIDE A1 CORNER INDEX IS A METALIZED FEATURE WITH VARIOUS SHAPES. BOTTOM SIDE. A1 CORNER IS DESIGNATED WITH A BALL MISSING FROM THE ARRAY.

	Millimeters	
DIM	MIN	MAX
A	2.72	3.20
A1	0.80	1.00
A2	1.10	1.30
A3	--	0.60
b	0.82	0.93
D	29.00 BSC	
D1	—	12.5
D2	8.5	—
D3	—	8.4
D4	10.9	11.1
e	1.27 BSC	
E	29.00 BSC	
E1	—	12.5
E2	8.5	—
E3	—	8.4
E4	9.55	9.75

Figure 22. Mechanical Dimensions and Bottom Surface Nomenclature for the MPC7457, 483 CBGA or RoHS BGA Package

8.6 Substrate Capacitors for the MPC7457, 483 CBGA or RoHS BGA

Figure 23 shows the connectivity of the substrate capacitor pads for the MPC7457, 483 CBGA or RoHS BGA. All capacitors are 100 nF.



Capacitor	Pad Number	
	-1	-2
C1	GND	OV_{DD}
C2	GND	V_{DD}
C3	GND	GV_{DD}
C4	GND	V_{DD}
C5	GND	V_{DD}
C6	GND	GV_{DD}
C7	GND	V_{DD}
C8	GND	V_{DD}
C9	GND	GV_{DD}
C10	GND	V_{DD}
C11	GND	V_{DD}
C12	GND	GV_{DD}
C13	GND	V_{DD}
C14	GND	V_{DD}
C15	GND	V_{DD}
C16	GND	OV_{DD}
C17	GND	V_{DD}
C18	GND	OV_{DD}
C19	GND	V_{DD}
C20	GND	V_{DD}
C21	GND	OV_{DD}
C22	GND	V_{DD}
C23	GND	V_{DD}
C24	GND	V_{DD}

Figure 23. Substrate Bypass Capacitors for the MPC7457, 483 CBGA or RoHS BGA

9 System Design Information

This section provides system and thermal design recommendations for successful application of the MPC7457.

9.1 Clocks

The following sections provide more detailed information regarding the clocking of the MPC7457.

9.1.1 Core Clocks and PLL Configuration

The MPC7457 PLL is configured by the PLL_CFG[0:4] signals. For a given SYSCLK (bus) frequency, the PLL configuration signals set the internal CPU and VCO frequency of operation. The PLL configuration for the MPC7457 is shown in Table 18 for a set of example frequencies. In this example, shaded cells represent settings that, for a given SYSCLK frequency, result in core and/or VCO frequencies that do not comply with the 1-GHz column in Table 8. Note that these configurations were different in some earlier MPC7450-family devices and care should be taken when upgrading to the MPC7457 to verify the correct PLL settings for an application.

Table 18. MPC7457 Microprocessor PLL Configuration Example for 1267 MHz Parts

PLL_CFG[0:4]	Bus-to-Core Multiplier	Core-to-VCO Multiplier	Example Bus-to-Core Frequency in MHz (VCO Frequency in MHz)							
			Bus (SYSCLK) Frequency							
			33.3 MHz	50 MHz	66.6 MHz	75 MHz	83 MHz	100 MHz	133 MHz	167 MHz
01000	2x	2x								
10000	3x	2x								
10100	4x	2x								667 (1333)
10110	5x	2x							667 (1333)	835 (1670)
10010	5.5x	2x							733 (1466)	919 (1837)
11010	6x	2x						600 (1200)	800 (1600)	1002 (2004)
01010	6.5x	2x						650 (1300)	866 (1730)	1086 (2171)
00100	7x	2x						700 (1400)	931 (1862)	1169 (2338)
00010	7.5x	2x					623 (1245)	750 (1500)	1000 (2000)	1253 (2505)
11000	8x	2x				600 (1200)	664 (1328)	800 (1600)	1064 (2128)	
01100	8.5x	2x				638 (1276)	706 (1412)	850 (1700)	1131 (2261)	

Table 18. MPC7457 Microprocessor PLL Configuration Example for 1267 MHz Parts (continued)

PLL_CFG[0:4]	Bus-to-Core Multiplier	Core-to-VCO Multiplier	Example Bus-to-Core Frequency in MHz (VCO Frequency in MHz)							
			Bus (SYSCLK) Frequency							
			33.3 MHz	50 MHz	66.6 MHz	75 MHz	83 MHz	100 MHz	133 MHz	167 MHz
01111	9x	2x			600 (1200)	675 (1350)	747 (1494)	900 (1800)	1197 (2394)	
01110	9.5x	2x			633 (1266)	712 (1524)	789 (1578)	950 (1900)	1264 (2528)	
10101	10x	2x			667 (1333)	750 (1500)	830 (1660)	1000 (2000)		
10001	10.5x	2x			700 (1400)	938 (1876)	872 (1744)	1050 (2100)		
10011	11x	2x			733 (1466)	825 (1650)	913 (1826)	1100 (2200)		
00000	11.5x	2x			766 (532)	863 (1726)	955 (1910)	1150 (2300)		
10111	12x	2x		600 (1200)	800 (1600)	900 (1800)	996 (1992)	1200 (2400)		
11111	12.5x	2x		600 (1200)	833 (1666)	938 (1876)	1038 (2076)	1250 (2500)		
01011	13x	2x		650 (1300)	865 (1730)	975 (1950)	1079 (2158)			
11100	13.5x	2x		675 (1350)	900 (1800)	1013 (2026)	1121 (2242)			
11001	14x	2x		700 (1400)	933 (1866)	1050 (2100)	1162 (2324)			
00011	15x	2x		750 (1500)	1000 (2000)	1125 (2250)	1245 (2490)			
11011	16x	2x		800 (1600)	1066 (2132)	1200 (2400)				
00001	17x	2x		850 (1900)	1132 (2264)					
00101	18x	2x	600 (1200)	900 (1800)	1200 (2400)					
00111	20x	2x	667 (1334)	1000 (2000)						
01001	21x	2x	700 (1400)	1050 (2100)						
01101	24x	2x	800 (1600)	1200 (2400)						
11101	28x	2x	933 (1866)							
00110	PLL bypass		PLL off, SYSCLK clocks core circuitry directly							

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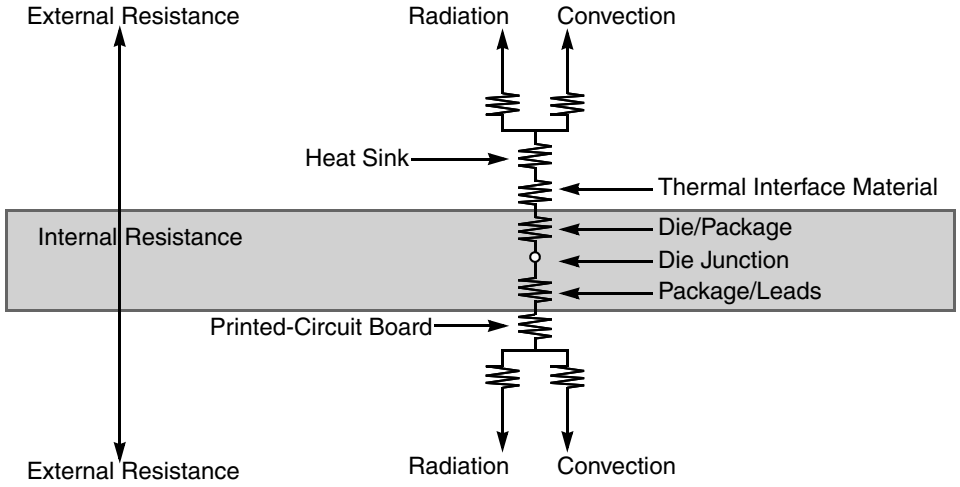
Ultimately, the final selection of an appropriate heat sink depends on many factors, such as thermal performance at a given air velocity, spatial volume, mass, attachment method, assembly, and cost.

9.8.1 Internal Package Conduction Resistance

For the exposed-die packaging technology, shown in Table 5, the intrinsic conduction thermal resistance paths are as follows:

- The die junction-to-case (actually top-of-die since silicon die is exposed) thermal resistance
- The die junction-to-ball thermal resistance

Figure 28 depicts the primary heat transfer path for a package with an attached heat sink mounted to a printed-circuit board.



(Note the internal versus external package resistance.)

Figure 28. C4 Package with Heat Sink Mounted to a Printed-Circuit Board

Heat generated on the active side of the chip is conducted through the silicon, through the heat sink attach material (or thermal interface material), and finally to the heat sink where it is removed by forced-air convection.

Because the silicon thermal resistance is quite small, for a first-order analysis, the temperature drop in the silicon may be neglected. Thus, the thermal interface material and the heat sink conduction/convective thermal resistances are the dominant terms.

Table 24. Part Numbers Addressed by MPC7457TRX*nnnn*LB Series Hardware Specifications Addendum (Document Order No. MPC7457ECS02AD)

MC	7457	T	RX	*nnnn*	L	*x*

Product Code	Part Identifier	Specification Modifier	Package	Processor Frequency	Application Modifier	Revision Level
MC	7457	T = Extended Temperature Device	RX = CBGA	1000 1267	L: 1.3 V ± 50 mV –40° to 105°C	C: 1.2; PVR = 8002 0102

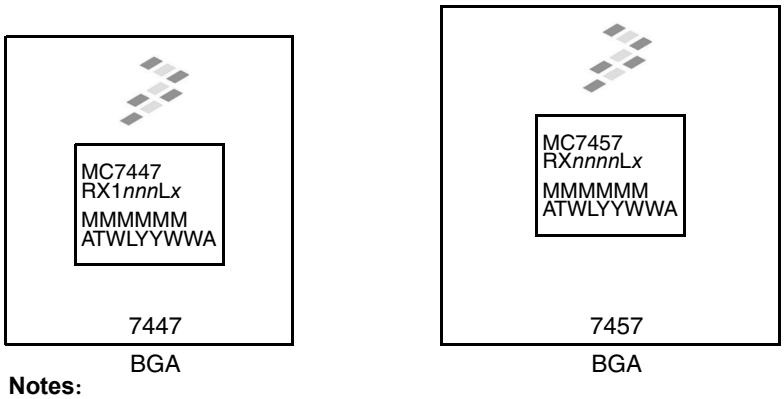
Table 25. Part Numbers Addressed by MPC7457TRX*nnnn*N*x* Series Hardware Specifications Addendum (Document Order No. MPC7457ECS03AD)

MC	74*x*7	T	RX	*nnnn*	N	*x*

Product Code	Part Identifier	Specification Modifier	Package	Processor Frequency	Application Modifier	Revision Level
MC	7447	T = Extended Temperature Device	RX = CBGA	733 1000	N: 1.1 V ± 50 mV –40° to 105°C	B: 1.1; PVR = 8002 0101
	7457					C: 1.2; PVR = 8002 0102

10.3 Part Marking

Parts are marked as the examples shown in Figure 31.



Notes:
MMMMMM is the 6-digit mask number.
ATWLYYWWA is the traceability code.

Figure 31. Part Marking for BGA Device

Table 26. Document Revision History (continued)

Revision Number	Date	Substantive Change(s)
4		Table 9: Corrected pin lists for input and output AC timing to correctly show $\overline{\text{HIT}}$ as an output-only signal
		Added specifications for 1267 MHz devices; removed specs for 1300 MHz devices.
		Section 5.2.3: Changed recommendations regarding use of L3 clock jitter in AC timing analysis. The L3 jitter is now fully comprehended in the AC timing specs and does not need to be included in the timing analysis.
3		Corrected numerous errors in lists of pins associated with t_{KHOV}, t_{KHOX}, t_{IVKH}, and t_{IXKH} in Table 9.
		Added support for 1.5 V L3 interface voltage; issues fixed in Rev. 1.1.
		Corrected typos in Table 12.
		Added data to Table 2.
		Clarified address bus pull-up resistor recommendations in Section 1.9.6.
		Modified Table 9, Figure 5, and Figure 6 to more accurately show when the mode select inputs ($\overline{\text{BMODE}}$[0:1], L3VSEL, BVSEL) are sampled and AC timing requirements
		Table 10: Added skew and jitter values.
		Table 14: Added AC timing values.
		Table 24: Updated to reflect past and current part numbers not fully covered by this document.
		Table 6: Removed CV_{IH} and CV_{IL}; V_{IH} and V_{IL} for SYSCLK input is the same as for other input signals, and is now noted accordingly in this table.
		Table 7: Removed Doze mode power entry (but left footnote 4 for clarity); documentation change only.
		Nontechnical formatting
2		Added substrate capacitor information in Sections 1.8.3 and 1.8.6.
		Increased minimum processor and VCO frequencies in Table 8 from 500 and 1000 MHz to 600 and 1200 MHz (respectively).
		Corrected maximum processor frequency for 1300 MHz devices in Table 8 (changed from 1333 to 1300 MHz).
		Added value for to $t_{L3CSKW1}$ Table 10.
		Added L3OHCR information in Section 1.5.2.4.1.
		Added values for t_{CO} and t_{ECI} to Table 11.
		Added Note 8 to Table 13 and Note 6 to Table 14.
		Changed resistor value in PLL filter in Figure 25 from 10 Ω to 400 Ω.
		Added 867 MHz speed grade.
		Corrected Product Code in Tables 22 and 23.
		Added pull-up/pull-down recommendations for $\overline{\text{CKSTP\_IN}}$ and PLL_CFG[0:4] to Section 1.9.6.
1.1		Nontechnical reformatting.